#### INTEGRATED CIRCUITS

## DATA SHEET

# **74LVTH244A**3.3V Octal buffer/line driver (3-State)

Propduct specification

1998 Oct 02

IC23 Data Handbook





## 3.3V Octal buffer/line driver (3-State)

#### **74LVTH244A**

#### **FEATURES**

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up 3-State
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### **DESCRIPTION**

The LVTH244A is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3V.

This device is an octal buffer that is ideal for driving bus lines. The device features two Output Enables ( $\overline{OE}1$ ,  $\overline{OE}2$ ), each controlling four of the 3-State outputs.

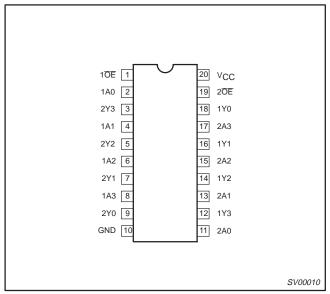
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	$C_L = 50$ pF; $V_{CC} = 3.3$ V	1.9 2.0	ns
C <sub>IN</sub>	Input capacitance	V <sub>I</sub> = 0V or 3.0V	4	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; V <sub>O</sub> = 0V or 3.0V	8	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6V	0.13	mA

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SOL	-40°C to +85°C	74LVTH244A D	74LVTH244A D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74LVTH244A DB	74LVTH244A DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVTH244A PW	7LVTH244APW DH	SOT360-1

#### PIN CONFIGURATION



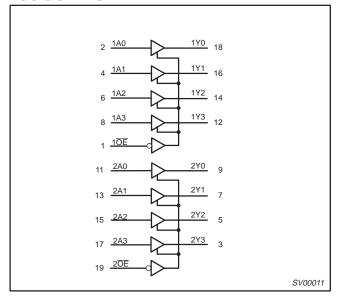
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
11. 13, 15, 17	2A0 – 2A3	Data inputs
18, 16, 14, 12	1Y0 – 1Y3	Data outputs
9, 7, 5, 3	2Y0 – 2Y3	Data outputs
1, 19	10E, 20E	Output enables
10	GND	Ground (0V)
20	V <sub>CC</sub>	Positive supply voltage

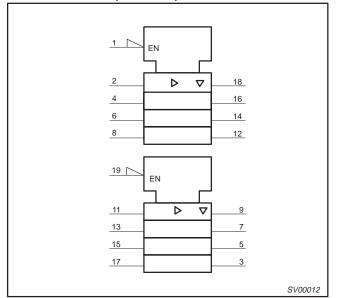
### 3.3V Octal buffer/line driver (3-State)

#### **74LVTH244A**

#### LOGIC SYMBOL



#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

INP	UTS	OUTPUTS
nOE1	nAx	nYx
L	L	L
L	Н	Н
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "off" state

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V	
VI	DC input voltage <sup>3</sup>		−0.5 to +7.0	V	
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	−0.5 to +7.0	V	
	DC output current	Output in Low state	128	mA	
Гоит	DC output current	Output in High state	-64	IIIA	
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	<b>–</b> 50	mA	
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA	
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C	

#### NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
  device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
  absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 3.3V Octal buffer/line driver (3-State)

#### **74LVTH244A**

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
3 TWIBOL	FARAMETER	MIN	MAX	ONIT
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-32	mA
lau	Low-level output current		32	mA
loL	Low-level output current; current duty cycle ≤ 50%, f ≥ 1kHz		64	ША
Δt/Δν	Input transition rise or fall rate; outputs enabled		10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

#### DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	: -40°C to -	-85°C	UNIT
				MIN	TYP <sup>1</sup>	MAX	1
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.9	-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub> -0.1		
$V_{OH}$	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.2		1
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.3	0.5	1
$V_{OL}$	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA			0.25	0.4	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.3	0.5	1
		$V_{CC} = 3.0V; I_{OL} = 64mA$		0.4	0.55	1	
		$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$			0.1	10	
	Input leakage current	$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1	μΑ
Η	Imput leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$	Data Pins <sup>4</sup>		0.1	1	μΑ
		$V_{CC} = 3.6V; V_{I} = 0$	Data i ilis		-1	-5	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V$ ; $V_I$ or $V_O = 0$ to 4.5V			1	±100	μΑ
		$V_{CC} = 3V; V_{I} = 0.8V$		75	130		
$I_{HOLD}$	Bus Hold current A inputs <sup>6</sup>	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-140		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I <sub>EX</sub>	Current into an output in the High state when V <sub>O</sub> > V <sub>CC</sub>	$V_O = 5.5V; V_{CC} = 3.0V$			60	125	μА
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GNI$ OE/ $\overline{OE} = Don't$ care	O or V <sub>CC</sub> ;		±1	±100	μΑ
l <sub>OZH</sub>	3-State output high current	$V_{CC} = 3.6V$ ; $V_O = 3V$ ; $V_I = V_{IL}$ or $V_{IH}$			1	5	μΑ
I <sub>OZL</sub>	3-State output low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			-1	<b>-</b> 5	μΑ
I <sub>CCH</sub>		$V_{CC} = 3.6V$ ; Outputs High, $V_{I} = GND$ or		0.13	0.19		
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V_{CC} = 0.6V$	V <sub>CC</sub> , I <sub>O</sub> = 0		2	5	mA
I <sub>CCZ</sub>	1	V <sub>CC</sub> = 3.6V; Outputs Disabled; V <sub>I</sub> = GNI	O or $V_{CC}$ , $I_{O} = 0^{5}$		0.13	0.19	1
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6 Other inputs at $V_{CC}$ or GND	V,		0.1	0.2	mA

#### NOTES:

- All typical values are at T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
   This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V and 1.2V in the company of the company transition time of 100 $\mu$ sec is permitted. This parameter is valid for  $T_{amb} = 25^{\circ}C$  only.

  4. Unused pins at  $V_{CC}$  or GND.

  5.  $I_{CCZ}$  is measured with outputs pulled to  $V_{CC}$  or GND.

- 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

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## 3.3V Octal buffer/line driver (3-State)

#### 74LVTH244A

#### **AC CHARACTERISTICS**

GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 500 $\Omega$ ;  $T_{amb}$  = -40°C to +85°C.

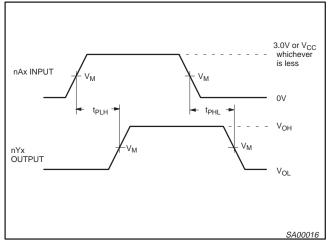
				L	IMITS		
SYMBOL	PARAMETER	WAVEFORM	Vc	$V_{CC} = 3.3V \pm 0.3V$		V <sub>CC</sub> = 2.7V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	1	1.1 1.3	1.9 2.0	3.5 3.3	3.8 3.6	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.1 1.4	2.8 2.3	4.5 4.4	5.3 4.9	ns
t <sub>PHZ</sub>	Output disable time from High and Low level	2	1.9 1.8	2.9 2.5	4.4 4.4	4.5 4.4	ns

#### NOTE:

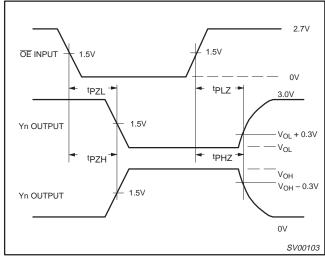
1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

#### **AC WAVEFORMS**

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 2.7V$ 



Waveform 1. Input (nAx) to Output (nYx) Propagation Delays

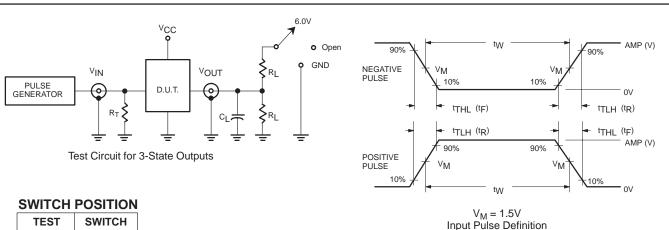


Waveform 2. 3-State Output Enable and Disable Times

## 3.3V Octal buffer/line driver (3-State)

#### 74LVTH244A

#### **TEST CIRCUIT AND WAVEFORMS**



TEST	SWITCH
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	6V
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L$  = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = Termination resistance should be equal to <math>Z_{OUT}$  of pulse generators.

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

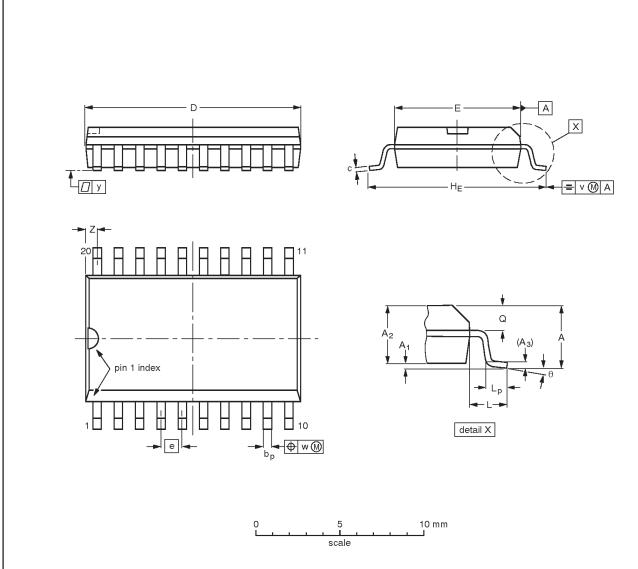
SV00092

## 3.3V Octal buffer/line driver (3-State)

#### 74LVTH244A

#### SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bp	O	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	ø	٧	w	у	z <sup>(1)</sup>	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

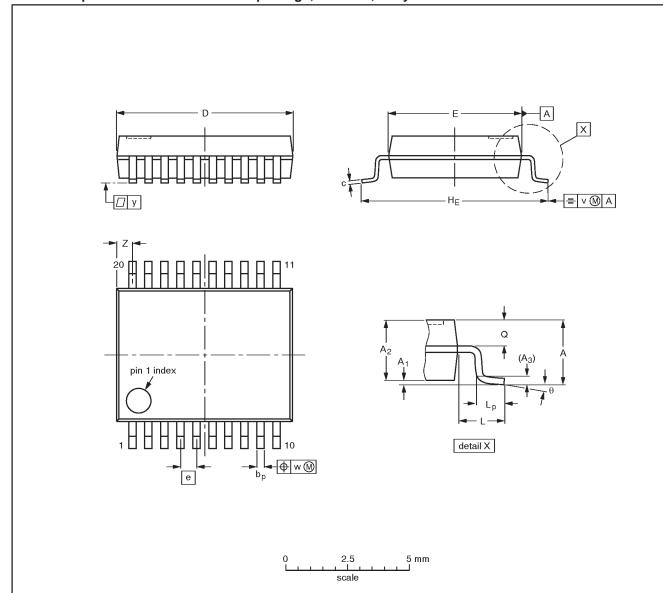
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1930E DATE	
SOT163-1	075E04	MS-013AC			<del>-92-11-17</del> 95-01-24	

## 3.3V Octal buffer/line driver (3-State)

#### 74LVTH244A

#### SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Ø	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

#### Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

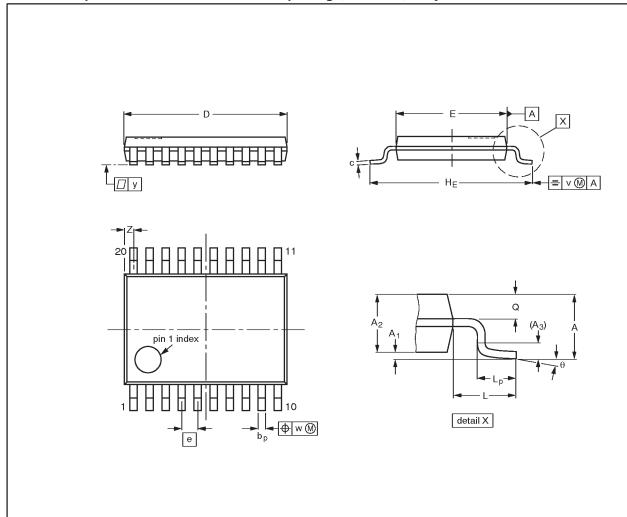
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT339-1		MO-150AE			<del>93-09-08</del> 95-02-04

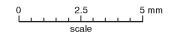
## 3.3V Octal buffer/line driver (3-State)

#### 74LVTH244A

#### TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1





#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	рb	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUEDATE
SOT360-1		MO-153AC			<del>-93-06-16-</del> 95-02-04

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#### 3.3V Octal buffer/line driver (3-State)

74LVTH244A

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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